## NSN 5961-00-497-4000

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View Online at https://aerobasegroup.com/nsn/5961-00-497-4000
Inclosure Material:
Metal
Overall Length:
Between 0.874 inches and 1.030 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 1.040 inches and 1.060 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 breakover voltage, dc
Current Rating Per Characteristic:
55.00 amperes source cutoff current of standard range
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
<del>-</del>
Demilitarization:
No
Fiig:
A110a0